NSN 5961-00-883-9495

Transistor - Page 1 of 1



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Iclosure Material: Metal Overall Length: 0.210 inches Terninal Length: 0.500 inches Overall Diameter: 0.230 inches Internal Configuration: 0.230 inches Internal Configuration: Junction contact Electocde Internally-electrically Connected To Case: Collector Mounting Method: Terminal Collo inches Features Provided: Hermetically sealed case Smiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, collector-to-base, doine to to to to topen
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25.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown
voltage emitter-to-base collector open
Power Rating Per Characteristic:
300.0 milliwatts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
80131-release3008 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
 Demilitarization:
No
Filg:
A110a0